LDMOS S-band radar power transistor

Rev. 3 — 1 September 2015

1. Product profile

1.1 General description

150 W LDMOS power transistor intended for radar applications in the 2.9 GHz to 3.3 GHz range.

Table 1.Typical performance

Typical RF performance at $T_{case} = 25 \ ^{\circ}C$; $t_p = 300 \ \mu s$; $\delta = 10 \ ^{\circ}$; $I_{Dq} = 100 \ mA$; in a class-AB production test circuit.

Mode of operation	f	V_{DS}	PL	G _p	η_D	t _r	t _f
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
pulsed RF	2.9 to 3.3	32	150	13.5	47	20	6

1.2 Features and benefits

- Typical pulsed RF performance at a frequency of 2.9 GHz to 3.3 GHz, a supply voltage of 32 V, an I_{Dq} of 100 mA, a t_p of 300 μs with δ of 10 %:
 - Output power = 150 W
 - Power gain = 13.5 dB
 - Efficiency = 47 %
- Easy power control
- Integrated ESD protection
- High flexibility with respect to pulse formats
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (2.9 GHz to 3.3 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

 S-band power amplifiers for radar applications in the 2.9 GHz to 3.3 GHz frequency range

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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	drain		
2	gate		1 لـــا
3	source		2

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information				
Type number Package				
	Name	Description	Version	
BLS7G2933S-150	-	ceramic earless flanged cavity package; 2 leads	SOT922-1	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V _{DS}	drain-source voltage	-	60	V
V _{GS}	gate-source voltage	-0.5	+13	V
I _D	drain current	-	33	А
T _{stg}	storage temperature	-65	+150	°C
Tj	junction temperature	-	200	°C

5. Thermal characteristics

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
Z _{th(j-mb)}	transient thermal impedance from junction	T_{case} = 85 °C; P _L = 150 W		
	to mounting base	t_p = 100 μ s; δ = 10 %	0.12	K/W
		t_p = 200 μ s; δ = 10 %	0.14	K/W
		t_p = 300 μ s; δ = 10 %	0.16	K/W
		t_p = 500 μ s; δ = 10 %	0.18	K/W
		t_p = 100 μ s; δ = 20 %	0.15	K/W

6. Characteristics

Table 6. Characteristics

 $T_j = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	V_{GS} = 0 V; I _D = 0.6 mA	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 180 mA	1.5	1.8	2.3	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 28 V	-	-	4.2	μA
I _{DSX}	drain cut-off current	$\label{eq:VGS} \begin{array}{l} V_{\mathrm{GS}} = V_{\mathrm{GS(th)}} + 3.75 \; V; \\ V_{\mathrm{DS}} = 10 \; V \end{array}$	29	35	-	A
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	420	nA
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 9 A	-	12.7	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ I _D = 6.3 A	-	0.085	0.135	Ω

7. Application information

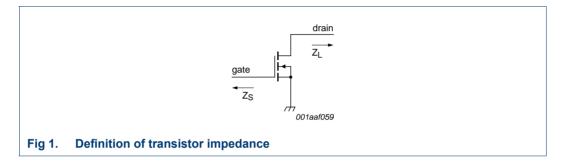
Table 7. Application information

Mode of operation: pulsed RF; $t_p = 300 \ \mu s$; $\delta = 10 \ \%$; RF performance at $V_{DS} = 32 \ V$; $I_{Dq} = 100 \ mA$; $T_{case} = 25 \ ^{\circ}C$; unless otherwise specified, in a class-AB production circuit.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
PL	output power		-	150	-	W
V _{CC}	supply voltage	P _L = 150 W	-	-	32	V
G _p	power gain	P _L = 150 W	11	13.5	-	dB
RL _{in}	input return loss	P _L = 150 W		-10	-5.5	dB
P _{L(1dB)}	output power at 1 dB gain compression		-	170	-	W
η _D	drain efficiency	P _L = 150 W	44	47	-	%
P _{droop(pulse)}	pulse droop power	P _L = 150 W	-	0	0.3	dB
t _r	rise time	P _L = 150 W	-	20	50	ns
t _f	fall time	P _L = 150 W	-	6	50	ns

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Table 8.	Typical impedance		
f		Z _S	ZL
GHz		Ω	Ω
2.9		2.2 – j7.4	4.2 – j6.3
3.0		2.9 – j6.5	3.8 - j6.4
3.1		4.2 – j5.9	3.4 – j6.3
3.2		6.0 – j6.5	2.9 - j6.2
3.3		6.5 – j8.9	2.5 – j5.9



7.1 Ruggedness in class-AB operation

The BLS7G2933S-150 is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dg} = 100 mA; P_L = 150 W; t_p = 300 μ s; δ = 10 %.

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BLS7G2933S-150

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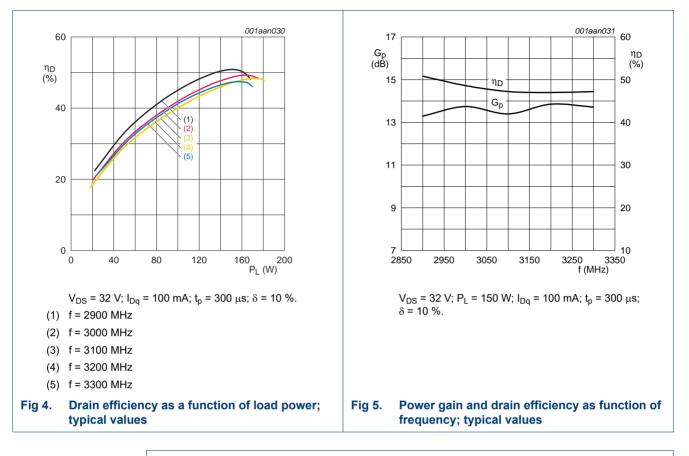
001aan028 001aan029 200 17 PL (W) G_p (dB) 160 15 (5) (4) (3) (2) (1) (1) (2) (3) (4) (5) 120 13 80 11 9 40 0 7 0 0 40 120 4 8 12 80 160 200 PL (W) P_i (W) V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %. V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %. (1) f = 2900 MHz (1) f = 2900 MHz (2) f = 3000 MHz (2) f = 3000 MHz (3) f = 3100 MHz (3) f = 3100 MHz (4) f = 3200 MHz (4) f = 3200 MHz (5) f = 3300 MHz (5) f = 3300 MHz Load power as a function of input power; Power gain as a function of load power; typical Fig 2. Fig 3. typical values values

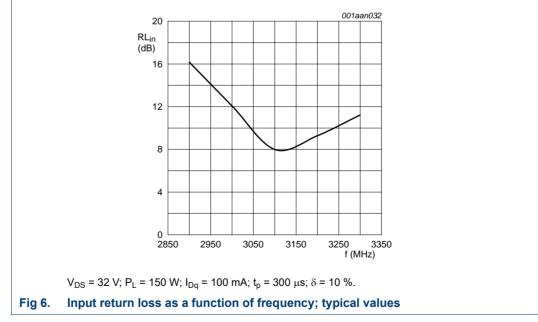
7.2 Graphs

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8. Test information

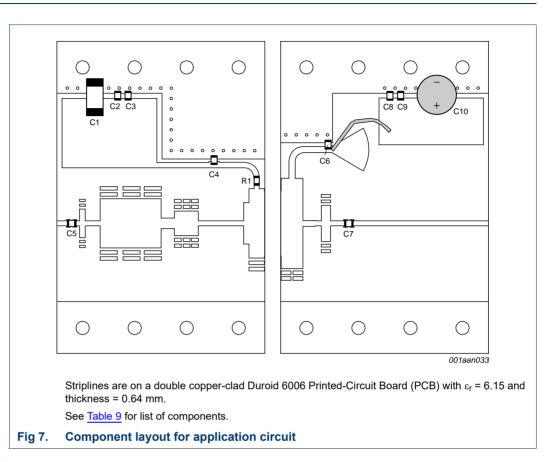


Table 9.List of componentsSee Figure 7.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	10 μF; 20 V	
C2, C8	multilayer ceramic chip capacitor	1 nF	ATC 700A or equivalent
C3, C9	multilayer ceramic chip capacitor	100 pF	ATC 100A or equivalent
C4, C5, C6, C7	multilayer ceramic chip capacitor	10 pF	ATC 100A or equivalent
C10	electrolytic capacitor	68 μF; 63 V	
R1	SMD resistor	10 Ω	SMD 0603

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9. Package outline

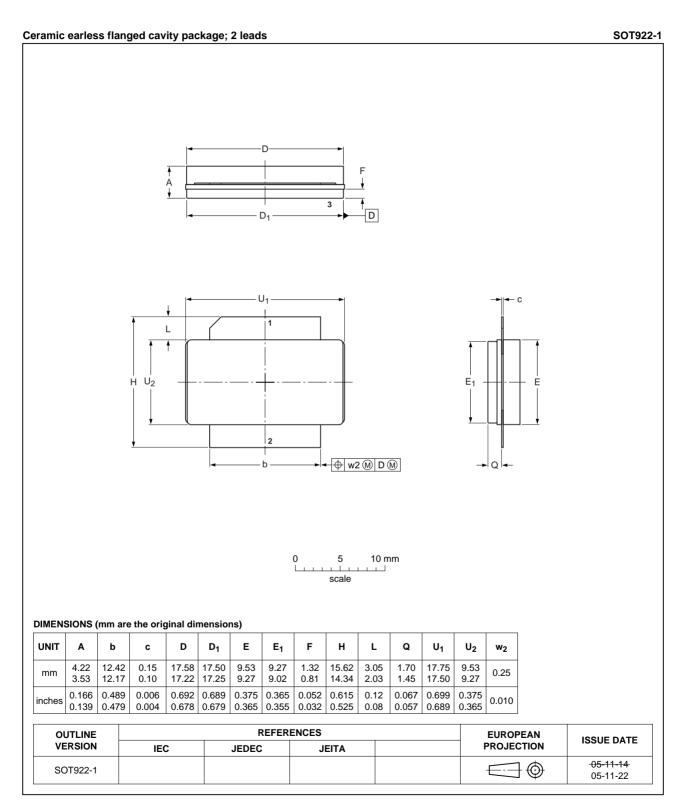


Fig 8. Package outline SOT922-1

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10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 10.	Table 10. Abbreviations		
Acronym	Description		
LDMOS	Laterally Diffused Metal-Oxide Semiconductor		
RF	Radio Frequency		
S-band	Short wave Band		
SMD	Surface Mounted Device		
VSWR	Voltage Standing-Wave Ratio		

12. Revision history

Table 11.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLS7G2933S-150#3	20150901	Product data sheet		BLS7G2933S-150 v.2	
Modifications:	guidelines of	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLS7G2933S-150 v.2	20110223	Product data sheet	-	BLS7G2933S-150 v.1	
BLS7G2933S-150 v.1	20101112	Objective data sheet	-	-	

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition	
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.	
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.	
Product [short] data sheet	Production	This document contains the product specification.	

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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